## Ming Yang

# List of Publications by Year in Descending Order

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68 5,641 41 175 h-index g-index citations papers 6,687 5.69 185 7.9 L-index avg, IF ext. papers ext. citations

#	Paper	IF	Citations
175	Flexible Sb0.405Te0.595 photodetectors with broadband spectral response up to 4.5 $\bar{\mu}$ m. <i>Acta Materialia</i> , <b>2022</b> , 226, 117631	8.4	O
174	Structure dependent and strain tunable magnetic ordering in ultrathin chromium telluride. <i>Journal of Alloys and Compounds</i> , <b>2022</b> , 893, 162223	5.7	2
173	A confinement approach to fabricate hybrid PBAs-derived FeCo@NC yolk-shell nanoreactors for bisphenol A degradation. <i>Chemical Engineering Journal</i> , <b>2022</b> , 428, 131080	14.7	3
172	Reply to: Detectivities of WS/HfS heterojunctions <i>Nature Nanotechnology</i> , <b>2022</b> ,	28.7	2
171	A first principles study of uniaxial strain-stabilized long@ange ferromagnetic ordering in electrenes. <i>Journal of Materials Chemistry C</i> , <b>2021</b> , 9, 16576-16580	7.1	1
170	Emergent Midgap Excitons in Large-Size Freestanding 2D Strongly Correlated Perovskite Oxide Films. <i>Advanced Optical Materials</i> , <b>2021</b> , 9, 2100025	8.1	2
169	Measurement of direct and indirect bandgaps in synthetic ultrathin MoS2 and WS2 films from photoconductivity spectra. <i>Journal of Applied Physics</i> , <b>2021</b> , 129, 155302	2.5	2
168	Internal photoemission of electrons from 2D semiconductor/3D metal barrier structures. <i>Journal Physics D: Applied Physics</i> , <b>2021</b> , 54, 295101	3	0
167	Emergent Midgap Excitons in Large-Size Freestanding 2D Strongly Correlated Perovskite Oxide Films (Advanced Optical Materials 10/2021). <i>Advanced Optical Materials</i> , <b>2021</b> , 9, 2170038	8.1	O
166	Tuning photoresponse of graphene-black phosphorus heterostructure by electrostatic gating and photo-induced doping. <i>Chinese Chemical Letters</i> , <b>2021</b> , 33, 368-368	8.1	1
165	AgS monolayer: an ultrasoft inorganic Lieb lattice. <i>Nanoscale</i> , <b>2021</b> , 13, 14008-14015	7.7	1
164	On-Surface Synthesis of Variable Bandgap Nanoporous Graphene. <i>Small</i> , <b>2021</b> , 17, e2102246	11	2
163	Room Temperature Ferromagnetism of Monolayer Chromium Telluride with Perpendicular Magnetic Anisotropy. <i>Advanced Materials</i> , <b>2021</b> , 33, e2103360	24	17
162	Design of novel pentagonal 2D transitional-metal sulphide monolayers for hydrogen evolution reaction. <i>International Journal of Hydrogen Energy</i> , <b>2020</b> , 45, 16201-16209	6.7	13
161	Correlated plasmons in the topological insulator Bi2Se3 induced by long-range electron correlations. <i>NPG Asia Materials</i> , <b>2020</b> , 12,	10.3	4
160	High-Throughput Identification of Exfoliable Two-Dimensional Materials with Active Basal Planes for Hydrogen Evolution. <i>ACS Energy Letters</i> , <b>2020</b> , 5, 2313-2321	20.1	28
159	Direct control of defects in molybdenum oxide and understanding their high CO2 sorption performance. <i>Journal of Materials Chemistry A</i> , <b>2020</b> , 8, 12576-12585	13	2

#### (2020-2020)

158	High oscillator strength interlayer excitons in two-dimensional heterostructures for mid-infrared photodetection. <i>Nature Nanotechnology</i> , <b>2020</b> , 15, 675-682	28.7	56	
157	Thermally Induced Chiral Aggregation of Dihydrobenzopyrenone on Au(111). <i>ACS Applied Materials &amp; Amp; Interfaces</i> , <b>2020</b> , 12, 35547-35554	9.5	2	
156	Performance Improvement by Ozone Treatment of 2D PdSe. ACS Nano, 2020, 14, 5668-5677	16.7	33	
155	Improving the interfacial properties of CZTS photocathodes by Ag substitution. <i>Journal of Materials Chemistry A</i> , <b>2020</b> , 8, 8862-8867	13	23	
154	Anisotropic Collective Charge Excitations in Quasimetallic 2D Transition-Metal Dichalcogenides. <i>Advanced Science</i> , <b>2020</b> , 7, 1902726	13.6	3	
153	Large-scale monolayer molybdenum disulfide (MoS2) for mid-infrared photonics. <i>Nanophotonics</i> , <b>2020</b> , 9, 4703-4710	6.3	3	
152	Transition-Metal Dichalcogenides: Anisotropic Collective Charge Excitations in Quasimetallic 2D Transition-Metal Dichalcogenides (Adv. Sci. 10/2020). <i>Advanced Science</i> , <b>2020</b> , 7, 2070055	13.6	1	
151	High-throughput screening of transition metal single atom catalysts anchored on molybdenum disulfide for nitrogen fixation. <i>Nano Energy</i> , <b>2020</b> , 68, 104304	17.1	75	
150	A novel layered birnessite-type sodium molybdate as dual-ion electrodes for high capacity battery. <i>Electrochimica Acta</i> , <b>2020</b> , 363, 137229	6.7	6	
149	Exciton-Enabled Meta-Optics in Two-Dimensional Transition Metal Dichalcogenides. <i>Nano Letters</i> , <b>2020</b> , 20, 7964-7972	11.5	5	
148	Interfacial Oxygen-Driven Charge Localization and Plasmon Excitation in Unconventional Superconductors. <i>Advanced Materials</i> , <b>2020</b> , 32, e2000153	24	6	
147	Surface Modification of Hematite Photoanodes with CeO Cocatalyst for Improved Photoelectrochemical Water Oxidation Kinetics. <i>ChemSusChem</i> , <b>2020</b> , 13, 5489-5496	8.3	8	
146	Black-Phosphorus-Incorporated Hydrogel as a Conductive and Biodegradable Platform for Enhancement of the Neural Differentiation of Mesenchymal Stem Cells. <i>Advanced Functional Materials</i> , <b>2020</b> , 30, 2000177	15.6	37	
145	Substrate mediated electronic and excitonic reconstruction in a MoS2 monolayer. <i>Journal of Materials Chemistry C</i> , <b>2020</b> , 8, 11778-11785	7.1	4	
144	Room-Temperature Colossal Magnetoresistance in Terraced Single-Layer Graphene. <i>Advanced Materials</i> , <b>2020</b> , 32, e2002201	24	12	
143	Memory Devices: MoS2/Polymer Heterostructures Enabling Stable Resistive Switching and Multistate Randomness (Adv. Mater. 42/2020). <i>Advanced Materials</i> , <b>2020</b> , 32, 2070317	24	1	
142	An energy efficient bi-functional electrode for continuous cation-selective capacitive deionization. <i>Nanoscale</i> , <b>2020</b> , 12, 22917-22927	7.7	7	
141	MoS /Polymer Heterostructures Enabling Stable Resistive Switching and Multistate Randomness.  Advanced Materials, 2020, 32, e2002704	24	11	

140	Co single-atom anchored on Co3O4 and nitrogen-doped active carbon toward bifunctional catalyst for zinc-air batteries. <i>Applied Catalysis B: Environmental</i> , <b>2020</b> , 260, 118188	21.8	94
139	Electronic correlation determining correlated plasmons in Sb-doped Bi2Se3. <i>Physical Review B</i> , <b>2019</b> , 100,	3.3	3
138	Far out-of-equilibrium spin populations trigger giant spin injection into atomically thin MoS2. <i>Nature Physics</i> , <b>2019</b> , 15, 347-351	16.2	68
137	Unraveling High-Yield Phase-Transition Dynamics in Transition Metal Dichalcogenides on Metallic Substrates. <i>Advanced Science</i> , <b>2019</b> , 6, 1802093	13.6	14
136	Energy Band Alignment of a Monolayer MoS2 with SiO2 and Al2O3 Insulators from Internal Photoemission. <i>Physica Status Solidi (A) Applications and Materials Science</i> , <b>2019</b> , 216, 1800616	1.6	9
135	Modulation of New Excitons in Transition Metal Dichalcogenide-Perovskite Oxide System. <i>Advanced Science</i> , <b>2019</b> , 6, 1900446	13.6	3
134	Discovery of Hidden Classes of Layered Electrides by Extensive High-Throughput Material Screening. <i>Chemistry of Materials</i> , <b>2019</b> , 31, 1860-1868	9.6	16
133	Employing a Bifunctional Molybdate Precursor To Grow the Highly Crystalline MoS for High-Performance Field-Effect Transistors. <i>ACS Applied Materials &amp; Description of the High-Performance Field-Effect Transistors</i> . <i>ACS Applied Materials &amp; Description of the Highly Crystalline MoS for High-Performance Field-Effect Transistors</i> . <i>ACS Applied Materials &amp; Description of the Highly Crystalline MoS for Highly Crystalline MoS fo</i>	48 <sup>5</sup>	4
132	Giant Enhancements of Perpendicular Magnetic Anisotropy and Spin-Orbit Torque by a MoS Layer. <i>Advanced Materials</i> , <b>2019</b> , 31, e1900776	24	40
131	The supramolecular structure and van der Waals interactions affect the electronic structure of ferrocenyl-alkanethiolate SAMs on gold and silver electrodes. <i>Nanoscale Advances</i> , <b>2019</b> , 1, 1991-2002	5.1	7
130	Modulating Charge Density Wave Order in a 1T-TaS/Black Phosphorus Heterostructure. <i>Nano Letters</i> , <b>2019</b> , 19, 2840-2849	11.5	13
129	Design of pentagonal NbX monolayers for electronics and electrocatalysis. <i>Applied Surface Science</i> , <b>2019</b> , 479, 595-600	6.7	11
128	Formation of two-dimensional small polarons at the conducting LaAlO3/SrTiO3 interface. <i>Physical Review B</i> , <b>2019</b> , 100,	3.3	3
127	Giant gate-tunable bandgap renormalization and excitonic effects in a 2D semiconductor. <i>Science Advances</i> , <b>2019</b> , 5, eaaw2347	14.3	37
126	Excitons: Modulation of New Excitons in Transition Metal Dichalcogenide-Perovskite Oxide System (Adv. Sci. 12/2019). <i>Advanced Science</i> , <b>2019</b> , 6, 1970073	13.6	2
125	Selective self-assembly of 2,3-diaminophenazine molecules on MoSe mirror twin boundaries. <i>Nature Communications</i> , <b>2019</b> , 10, 2847	17.4	17
124	Diindenoperylene thin-film structure on MoS2 monolayer. <i>Applied Physics Letters</i> , <b>2019</b> , 114, 251906	3.4	10
123	Gate-Tunable In-Plane Ferroelectricity in Few-Layer SnS. <i>Nano Letters</i> , <b>2019</b> , 19, 5109-5117	11.5	80

#### (2018-2019)

122	Tunable spin and orbital polarization in SrTiO3-based heterostructures. <i>New Journal of Physics</i> , <b>2019</b> , 21, 103016	2.9	3
121	Revealing the Grain Boundary Formation Mechanism and Kinetics during Polycrystalline MoS Growth. <i>ACS Applied Materials &amp; Discreta (Materials &amp; Materials &amp; Materi</i>	9.5	17
120	Three-Dimensional Resonant Exciton in Monolayer Tungsten Diselenide Actuated by Spin-Orbit Coupling. <i>ACS Nano</i> , <b>2019</b> , 13, 14529-14539	16.7	5
119	Atomically Thin 2D Transition Metal Oxides: Structural Reconstruction, Interaction with Substrates, and Potential Applications. <i>Advanced Materials Interfaces</i> , <b>2019</b> , 6, 1801160	4.6	63
118	Understanding the Roles of NiO in Enhancing the Photoelectrochemical Performance of BiVO Photoanodes for Solar Water Splitting. <i>ChemSusChem</i> , <b>2019</b> , 12, 2022-2028	8.3	21
117	Electronic properties of atomically thin MoS layers grown by physical vapour deposition: band structure and energy level alignment at layer/substrate interfaces RSC Advances, 2018, 8, 7744-7752	3.7	15
116	Large Enhancement of 2D Electron Gases Mobility Induced by Interfacial Localized Electron Screening Effect. <i>Advanced Materials</i> , <b>2018</b> , 30, e1707428	24	10
115	Modification of Vapor Phase Concentrations in MoS Growth Using a NiO Foam Barrier. <i>ACS Nano</i> , <b>2018</b> , 12, 1339-1349	16.7	62
114	Self-Anchored Catalyst Interface Enables Ordered Via Array Formation from Submicrometer to Millimeter Scale for Polycrystalline and Single-Crystalline Silicon. <i>ACS Applied Materials &amp; Amp; Interfaces</i> , <b>2018</b> , 10, 9116-9122	9.5	17
113	Large valley splitting in monolayer WS2 by proximity coupling to an insulating antiferromagnetic substrate. <i>Physical Review B</i> , <b>2018</b> , 97,	3.3	76
112	Phonon-Mediated Colossal Magnetoresistance in Graphene/Black Phosphorus Heterostructures. <i>Nano Letters</i> , <b>2018</b> , 18, 3377-3383	11.5	21
111	Band alignment of 2D WS2/HfO2 interfaces from x-ray photoelectron spectroscopy and first-principles calculations. <i>Applied Physics Letters</i> , <b>2018</b> , 112, 171604	3.4	12
110	3D heterostructured pure and N-Doped Ni3S2/VS2 nanosheets for high efficient overall water splitting. <i>Electrochimica Acta</i> , <b>2018</b> , 269, 55-61	6.7	91
109	Defect Evolution Enhanced Visible-Light Photocatalytic Activity in Nitrogen-Doped Anatase TiO2 Thin Films. <i>Journal of Physical Chemistry C</i> , <b>2018</b> , 122, 16600-16606	3.8	15
108	Robust two-dimensional bipolar magnetic semiconductors by defect engineering. <i>Journal of Materials Chemistry C</i> , <b>2018</b> , 6, 8435-8443	7.1	12
107	Hydrogen Evolution Catalyzed by a Molybdenum Sulfide Two-Dimensional Structure with Active Basal Planes. <i>ACS Applied Materials &amp; Samp; Interfaces</i> , <b>2018</b> , 10, 22042-22049	9.5	15
106	Direct Observation of Room-Temperature Stable Magnetism in LaAlO/SrTiO Heterostructures. <i>ACS Applied Materials &amp; Discourse (Materials &amp; Discourse)</i> 10, 9774-9781	9.5	9
105	Band alignment at interfaces of synthetic few-monolayer MoS2 with SiO2 from internal photoemission. <i>APL Materials</i> , <b>2018</b> , 6, 026801	5.7	15

104	High-Throughput Computational Screening of Vertical 2D van der Waals Heterostructures for High-efficiency Excitonic Solar Cells. <i>ACS Applied Materials &amp; amp; Interfaces</i> , <b>2018</b> , 10, 32142-32150	9.5	41
103	Direct observation of anisotropic small-hole polarons in an orthorhombic structure of BiVO4 films. <i>Physical Review B</i> , <b>2018</b> , 97,	3.3	3
102	Tailoring sample-wide pseudo-magnetic fields on a graphene-black phosphorus heterostructure. <i>Nature Nanotechnology</i> , <b>2018</b> , 13, 828-834	28.7	74
101	Facile Synthesis of Vanadium-Doped NiS Nanowire Arrays as Active Electrocatalyst for Hydrogen Evolution Reaction. <i>ACS Applied Materials &amp; Amp; Interfaces</i> , <b>2017</b> , 9, 5959-5967	9.5	138
100	Au/Ni12P5 core/shell single-crystal nanoparticles as oxygen evolution reaction catalyst. <i>Nano Research</i> , <b>2017</b> , 10, 3103-3112	10	41
99	Prospects of spintronics based on 2D materials. <i>Wiley Interdisciplinary Reviews: Computational Molecular Science</i> , <b>2017</b> , 7, e1313	7.9	105
98	Tunable and low-loss correlated plasmons in Mott-like insulating oxides. <i>Nature Communications</i> , <b>2017</b> , 8, 15271	17.4	30
97	Revealing the Role of Potassium Treatment in CZTSSe Thin Film Solar Cells. <i>Chemistry of Materials</i> , <b>2017</b> , 29, 4273-4281	9.6	31
96	Minimizing Isolate Catalyst Motion in Metal-Assisted Chemical Etching for Deep Trenching of Silicon Nanohole Array. <i>ACS Applied Materials &amp; Samp; Interfaces</i> , <b>2017</b> , 9, 20981-20990	9.5	27
95	Tuning Contact Barrier Height between Metals and MoS2 Monolayer through Interface Engineering. <i>Advanced Materials Interfaces</i> , <b>2017</b> , 4, 1700035	4.6	14
94	Pressure induced topological phase transition in layered BiS. <i>Physical Chemistry Chemical Physics</i> , <b>2017</b> , 19, 29372-29380	3.6	12
93	Tunable Fluorescence Properties Due to Carbon Incorporation in Zinc Oxide Nanowires. <i>Advanced Optical Materials</i> , <b>2017</b> , 5, 1700381	8.1	7
92	Damage-Free Smooth-Sidewall InGaAs Nanopillar Array by Metal-Assisted Chemical Etching. <i>ACS Nano</i> , <b>2017</b> , 11, 10193-10205	16.7	26
91	Efficient coupling of a hierarchical V2O5@Ni3S2 hybrid nanoarray for pseudocapacitors and hydrogen production. <i>Journal of Materials Chemistry A</i> , <b>2017</b> , 5, 17954-17962	13	61
90	La interstitial defect-induced insulator-metal transition in the oxide heterostructures LaAlO3/SrTiO3. <i>Physical Review B</i> , <b>2017</b> , 96,	3.3	6
89	Si24: An Efficient Solar Cell Material. <i>Journal of Physical Chemistry C</i> , <b>2017</b> , 121, 15574-15579	3.8	13
88	Synergistic effect of 2D Ti2C and g-C3N4 for efficient photocatalytic hydrogen production. <i>Journal of Materials Chemistry A</i> , <b>2017</b> , 5, 16748-16756	13	141
87	Giant crystalline anisotropic magnetoresistance in nonmagnetic perovskite oxide heterostructures. <i>Physical Review B</i> , <b>2017</b> , 95,	3.3	14

#### (2015-2017)

86	Layer-dependent semiconductor-metal transition of SnO/Si(001) heterostructure and device application. <i>Scientific Reports</i> , <b>2017</b> , 7, 2570	4.9	2
85	Electronic and optical properties of the monolayer group-IV monochalcogenides MX (M=Ge,Sn; X=S,Se,Te). <i>Physical Review B</i> , <b>2017</b> , 95,	3.3	129
84	Abnormal behavior of potassium adsorbed phosphorene. <i>International Journal of Computational Materials Science and Engineering</i> , <b>2017</b> , 06, 1850002	0.3	
83	Achieving giant tunneling electroresistance and magnetoresistance by BaTiO3/SrTiO3 barrier and Heusler alloy electrode. <i>Physical Review Materials</i> , <b>2017</b> , 1,	3.2	3
82	Immobilization of dye pollutants on iron hydroxide coated substrates: kinetics, efficiency and the adsorption mechanism. <i>Journal of Materials Chemistry A</i> , <b>2016</b> , 4, 13280-13288	13	42
81	The stability of aluminium oxide monolayer and its interface with two-dimensional materials. <i>Scientific Reports</i> , <b>2016</b> , 6, 29221	4.9	39
80	Tuning polarization states and interface properties of BaTiO3/SrTiO3 heterostructure by metal capping layers. <i>Physical Review B</i> , <b>2016</b> , 93,	3.3	5
79	Giant tunneling electroresistance induced by ferroelectrically switchable two-dimensional electron gas at nonpolar BaTiO3/SrTiO3 interface. <i>Physical Review B</i> , <b>2016</b> , 94,	3.3	11
78	Orbital dependent ultrafast charge transfer dynamics of ferrocenyl-functionalized SAMs on gold studied by core-hole clock spectroscopy. <i>Journal of Physics Condensed Matter</i> , <b>2016</b> , 28, 094006	1.8	7
77	Coordination polymer structure and revisited hydrogen evolution catalytic mechanism for amorphous molybdenumßulfide. <i>Nature Materials</i> , <b>2016</b> , 15, 640-6	27	379
76	Evidences for redox reaction driven charge transfer and mass transport in metal-assisted chemical etching of silicon. <i>Scientific Reports</i> , <b>2016</b> , 6, 36582	4.9	26
75	Interfacial Interaction between HfO2 and MoS2: From Thin Films to Monolayer. <i>Journal of Physical Chemistry C</i> , <b>2016</b> , 120, 9804-9810	3.8	23
74	Substoichiometric Molybdenum Sulfide Phases with Catalytically Active Basal Planes. <i>Journal of the American Chemical Society</i> , <b>2016</b> , 138, 14121-14128	16.4	22
73	Detrimental Effects of Oxygen Vacancies in Electrochromic Molybdenum Oxide. <i>Journal of Physical Chemistry C</i> , <b>2015</b> , 119, 10592-10601	3.8	38
72	Large-scale two-dimensional MoSIphotodetectors by magnetron sputtering. <i>Optics Express</i> , <b>2015</b> , 23, 13580-6	3.3	74
71	Optical conductivity renormalization of graphene on SrTiO3 due to resonant excitonic effects mediated by Ti 3d orbitals. <i>Physical Review B</i> , <b>2015</b> , 91,	3.3	19
70	Band Bending Inversion in Bi2Se3 Nanostructures. <i>Nano Letters</i> , <b>2015</b> , 15, 7503-7	11.5	29
69	Graphene stabilized high-Idielectric Y2O3 (111) monolayers and their interfacial properties. <i>RSC Advances</i> , <b>2015</b> , 5, 83588-83593	3.7	14

68	Electronic and transport properties of phosphorene nanoribbons. <i>Physical Review B</i> , <b>2015</b> , 92,	3.3	105
67	Topological properties determined by atomic buckling in self-assembled ultrathin Bi(110). <i>Nano Letters</i> , <b>2015</b> , 15, 80-7	11.5	131
66	Ferromagnetism of wide-bandgap semiconductor surfaces: Mg-doped AlN. <i>Japanese Journal of Applied Physics</i> , <b>2015</b> , 54, 110302	1.4	2
65	Interplay of electronic reconstructions, surface oxygen vacancies, and lattice distortions in insulator-metal transition of LaAlO3/SrTiO3. <i>Physical Review B</i> , <b>2015</b> , 92,	3.3	30
64	Temperature dependence of photoluminescence spectra of bilayer two-dimensional electron gases in LaAlO3/SrTiO3 superlattices: coexistence of Auger recombination and single-carrier trapping. <i>AIP Advances</i> , <b>2015</b> , 5, 067163	1.5	4
63	The effect of oxygen vacancies on the electronic structures, magnetic properties and the stability of SrTiO3(001) surface. <i>Surface Science</i> , <b>2015</b> , 641, 37-50	1.8	7
62	Atomic N Modified Rutile TiO2(110) Surface Layer with Significant Visible Light Photoactivity. Journal of Physical Chemistry C, <b>2014</b> , 118, 994-1000	3.8	26
61	Giant enhancement in vertical conductivity of stacked CVD graphene sheets by self-assembled molecular layers. <i>Nature Communications</i> , <b>2014</b> , 5, 5461	17.4	61
60	Biaxial strain-induced transport property changes in atomically tailored SrTiO3-based systems. <i>Physical Review B</i> , <b>2014</b> , 90,	3.3	32
59	Efficient Spin Injection into Graphene through a Tunnel Barrier: Overcoming the Spin-Conductance Mismatch. <i>Physical Review Applied</i> , <b>2014</b> , 2,	4.3	33
58	Surface magnetism of Mg doped AlN: a first principle study. <i>Journal of Physics Condensed Matter</i> , <b>2014</b> , 26, 435801	1.8	4
57	The energy-band alignment at molybdenum disulphide and high-k dielectrics interfaces. <i>Applied Physics Letters</i> , <b>2014</b> , 104, 232110	3.4	46
56	Band alignment and interfacial structure of ZnO/Si heterojunction with Al2O3 and HfO2 as interlayers. <i>Applied Physics Letters</i> , <b>2014</b> , 104, 161602	3.4	35
55	Reversible room-temperature ferromagnetism in Nb-doped SrTiO3 single crystals. <i>Physical Review B</i> , <b>2013</b> , 87,	3.3	25
54	Simultaneous magnetic and charge doping of topological insulators with carbon. <i>Physical Review Letters</i> , <b>2013</b> , 111, 236803	7.4	12
53	Orientation control of epitaxial Ge thin films growth on SrTiO3 (100) by ultrahigh vacuum sputtering. <i>Thin Solid Films</i> , <b>2012</b> , 520, 4880-4883	2.2	1
52	First-Principles Study of Hydrogenation of Ethylene on a HxMoO3(010) Surface. <i>Journal of Physical Chemistry C</i> , <b>2012</b> , 116, 24630-24638	3.8	23
51	First-principles study of the effect of BiGa heteroantisites in GaAs:Bi alloy. <i>Computational Materials Science</i> , <b>2012</b> , 63, 178-181	3.2	11

### (2010-2012)

50	Graphene Oxide: An Ideal Support for Gold Nanocatalysts. <i>Journal of Physical Chemistry C</i> , <b>2012</b> , 116, 22336-22340	3.8	44
49	Copper molybdenum sulfide: a new efficient electrocatalyst for hydrogen production from water. Energy and Environmental Science, <b>2012</b> , 5, 8912	35.4	274
48	Interfacial Properties of Silicon Nitride Grown on Epitaxial Graphene on 6H-SiC Substrate. <i>Journal of Physical Chemistry C</i> , <b>2012</b> , 116, 22315-22318	3.8	10
47	First principles study of the ternary complex model of EL2 defect in GaAs saturable absorber. <i>Optics Express</i> , <b>2012</b> , 20, 6258-66	3.3	22
46	First principles study of bismuth alloying effects in GaAs saturable absorber. <i>Optics Express</i> , <b>2012</b> , 20, 11574-80	3.3	18
45	Tailoring the electronic properties of SrRuO3 films in SrRuO3/LaAlO3 superlattices. <i>Applied Physics Letters</i> , <b>2012</b> , 101, 223105	3.4	17
44	Magnetic and transport properties of Mn3\(\text{MgO/Mn3\(\text{MgO}\)}\) and the magnetic tunnel junctions: A first-principles study. Applied Physics Letters, 2012, 100, 022408	3.4	45
43	Effect of interfacial strain on spin injection and spin polarization of Co 2 CrAl/NaNbO 3 /Co 2 CrAl magnetic tunneling junction. <i>Europhysics Letters</i> , <b>2012</b> , 99, 37001	1.6	10
42	Charge and spin transport in graphene-based heterostructure. <i>Applied Physics Letters</i> , <b>2011</b> , 98, 053107	1 3.4	59
41	Hexagonal TiO2 for Photoelectrochemical Applications. <i>Journal of Physical Chemistry C</i> , <b>2011</b> , 115, 180	42 <del>,</del> \$80	1 <b>45</b> 5
40	Manipulating absorption and diffusion of H atom on graphene by mechanical strain. <i>AIP Advances</i> , <b>2011</b> , 1, 032109	1.5	24
39	Fabrication of a \$hbox{TiN}_{x}/hbox{Ni/Au}\$ Contact on ZnO Films With High Thermal Stability and Low Resistance. <i>IEEE Transactions on Electron Devices</i> , <b>2011</b> , 58, 4297-4300	2.9	1
38	Graphene on Esi3N4: An ideal system for graphene-based electronics. AIP Advances, 2011, 1, 032111	1.5	19
37	First-principles study of NiSi2/HfO2interfaces: energetics and Schottky-barrier heights. <i>Journal Physics D: Applied Physics</i> , <b>2011</b> , 44, 405302	3	
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35	Effects of nitrogen incorporation on the electronic structure of rutile-TiO2. <i>Journal of Applied Physics</i> , <b>2011</b> , 109, 023707	2.5	10
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31	Atomic and electronic structures at ZnO and ZrO2 interface for transparent thin-film transistors. <i>Physica Status Solidi (A) Applications and Materials Science</i> , <b>2010</b> , 207, 1731-1734	1.6	13
30	Band offsets of HfO2/ZnO interface: In situ x-ray photoelectron spectroscopy measurement and ab initio calculation. <i>Applied Physics Letters</i> , <b>2009</b> , 95, 162104	3.4	26
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18	Band alignment and thermal stability of HfO2 gate dielectric on SiC. <i>Applied Physics Letters</i> , <b>2008</b> , 93, 052104	3.4	20
17	Possible efficient p-type doping of AlN using Be: An ab initio study. <i>Applied Physics Letters</i> , <b>2007</b> , 91, 152110	3.4	16
16	Electronic structure of germanium nitride considered for gate dielectrics. <i>Journal of Applied Physics</i> , <b>2007</b> , 102, 013507	2.5	32
15	Ab initio study on intrinsic defect properties of germanium nitride considered for gate dielectric. <i>Applied Physics Letters</i> , <b>2007</b> , 91, 132906	3.4	9

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14	Effect of nitrogen incorporation on the electronic structure and thermal stability of HfO2 gate dielectric. <i>Applied Physics Letters</i> , <b>2006</b> , 88, 192103	3.4	56	
13	Thermal stability and band alignments for Ge3N4 dielectrics on Ge. <i>Applied Physics Letters</i> , <b>2006</b> , 89, 022105	3.4	53	
12	Impact of interface structure on Schottky-barrier height for NiZrO2(001) interfaces. <i>Applied Physics Letters</i> , <b>2005</b> , 86, 132103	3.4	43	
11	First-principles study of ZrO2Bi interfaces: Energetics and band offsets. <i>Physical Review B</i> , <b>2005</b> , 72,	3.3	53	
10	Photoemission study of energy-band alignment for RuOxHfO2Bi system. <i>Applied Physics Letters</i> , <b>2004</b> , 85, 6155-6157	3.4	34	
9	Effect of doping SiO2 on high-frequency magnetic properties for W-type barium ferrite. <i>Journal of Applied Physics</i> , <b>2004</b> , 95, 4235-4239	2.5	36	
8	Energy-band alignments at ZrO2Bi, SiGe, and Ge interfaces. <i>Applied Physics Letters</i> , <b>2004</b> , 85, 4418	3.4	56	
7	Reaction of SiO2 with hafnium oxide in low oxygen pressure. <i>Applied Physics Letters</i> , <b>2003</b> , 82, 2047-20	<b>43</b> .4	82	
6	Epitaxial Y-stabilized ZrO2 films on silicon: Dynamic growth process and interface structure. <i>Applied Physics Letters</i> , <b>2002</b> , 80, 2541-2543	3.4	96	
5	Crystalline zirconia oxide on silicon as alternative gate dielectrics. <i>Applied Physics Letters</i> , <b>2001</b> , 78, 160	)4 <u>3</u> 14606	5 82	
4	Microstructure and growth mode at early growth stage of laser-ablated epitaxial Pb(Zr0.52Ti0.48)O3 films on a SrTiO3 substrate. <i>Journal of Applied Physics</i> , <b>2001</b> , 89, 4497-4502	2.5	22	
3	Oxygen-deficiency-activated charge ordering in La2/3Sr1/3MnO3Ithin films. <i>Applied Physics Letters</i> , <b>2000</b> , 76, 1051-1053	3.4	42	
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